

ZX5T851G

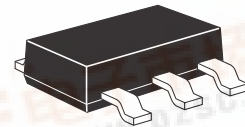
60V NPN MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

SUMMARY

$BV_{CEO} = 60V$; $R_{SAT} = 35m\Omega$; $I_C = 6A$

DESCRIPTION

Packaged in the SOT223 outline this new 5th generation low saturation 60V NPN transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.



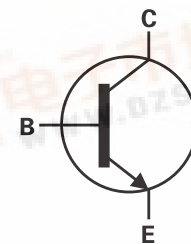
SOT223

FEATURES

- Extremely low equivalent on-resistance; $R_{SAT} = 35mV$ at 6A
- 6 amps continuous current
- Up to 20 amps peak current
- Very low saturation voltages
- Excellent h_{FE} characteristics up to 10 amps

APPLICATIONS

- Emergency lighting circuits
- Motor driving (including DC fans)
- Solenoid, relay and actuator drivers
- DC Modules
- Backlight Inverters



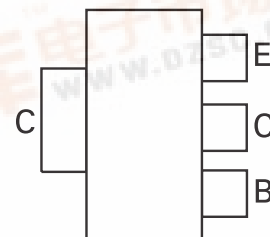
ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL
ZX5T851GTA	7"	12mm	1000 units
ZX5T851GTC	13"	embossed	4000 units

DEVICE MARKING

- X5T851

PINOUT



TOP VIEW

ZX5T851G

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-base voltage	BV_{CBO}	150	V
Collector-emitter voltage	BV_{CEO}	60	V
Emitter-base voltage	BV_{EBO}	7	V
Continuous collector current ^(a)	I_C	6	A
Peak pulse current	I_{CM}	20	A
Power dissipation at $T_A = 25^\circ\text{C}$ ^(a)	P_D	3.0	W
Linear derating factor		24	mW/ $^\circ\text{C}$
Power dissipation at $T_A = 25^\circ\text{C}$ ^(b)	P_D	1.6	W
Linear derating factor		12.8	mW/ $^\circ\text{C}$
Operating and storage temperature range	T_j, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to ambient ^(a)	$R_{\theta JA}$	42	$^\circ\text{C/W}$

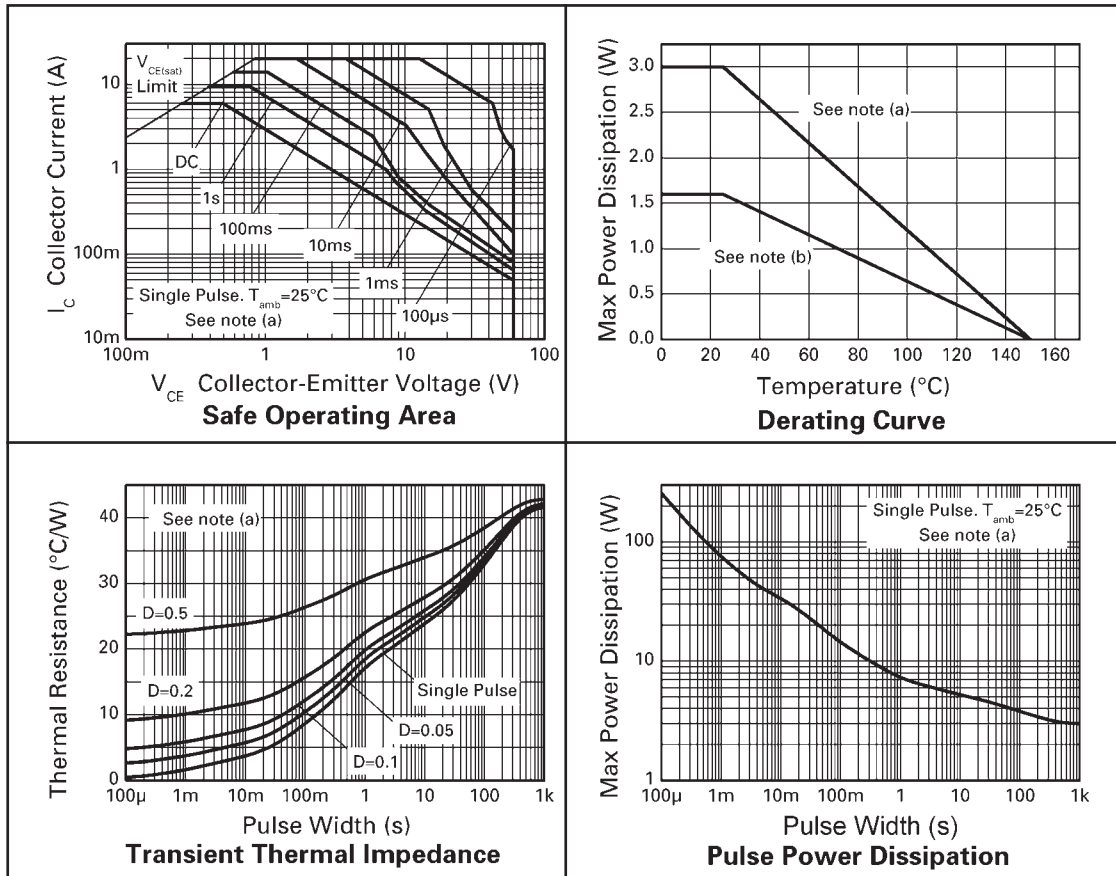
NOTES

(a) For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

(b) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

ZX5T851G

CHARACTERISTICS



ZX5T851G

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

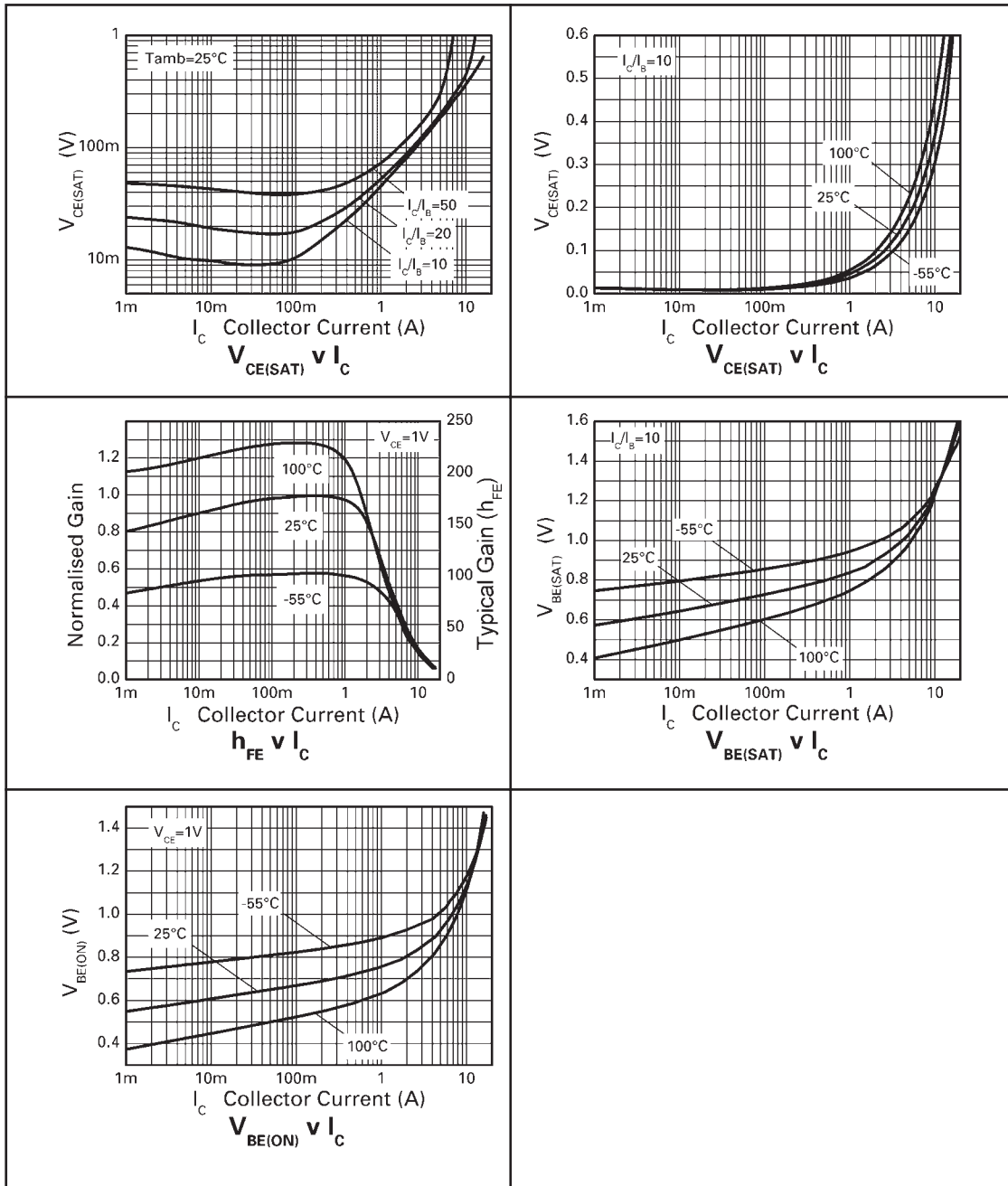
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-base breakdown voltage	BV_{CBO}	150	190		V	$I_C=100\mu\text{A}$
Collector-emitter breakdown voltage	BV_{CER}	150	190		V	$I_C=1\mu\text{A}$, $R_B \leq 1\text{k}\Omega$
Collector-emitter breakdown voltage	BV_{CEO}	60	80		V	$I_C=10\text{mA}^*$
Emitter-base breakdown voltage	BV_{EBO}	7	8.1		V	$I_E=100\mu\text{A}$
Collector cut-off current	I_{CBO}			20 0.5	nA μA	$V_{CB}=120\text{V}$ $V_{CB}=120\text{V}$, $T_{amb}=100^{\circ}\text{C}$
Collector cut-off current	I_{CER} $R \leq 1\text{k}\Omega$			20 0.5	nA μA	$V_{CB}=120\text{V}$ $V_{CB}=120\text{V}$, $T_{amb}=100^{\circ}\text{C}$
Emitter cut-off current	I_{EBO}			10	nA	$V_{EB}=6\text{V}$
Collector-emitter saturation voltage	$V_{CE(SAT)}$		20 45 50 100 210	30 60 70 135 260	mV mV mV mV mV	$I_C=100\text{mA}$, $I_B=5\text{mA}^*$ $I_C=1\text{A}$, $I_B=100\text{mA}^*$ $I_C=1\text{A}$, $I_B=50\text{mA}^*$ $I_C=2\text{A}$, $I_B=50\text{mA}^*$ $I_C=6\text{A}$, $I_B=300\text{mA}^*$
Base-emitter saturation voltage	$V_{BE(SAT)}$		1000	1100	mV	$I_C=6\text{A}$, $I_B=300\text{mA}^*$
Base-emitter turn-on voltage	$V_{BE(ON)}$		940	1050	mV	$I_C=6\text{A}$, $V_{CE}=1\text{V}^*$
Static forward current transfer ratio	H_{FE}	100 100 55 20	200 200 105 40	300		$I_C=10\text{mA}$, $V_{CE}=1\text{V}^*$ $I_C=2\text{A}$, $V_{CE}=1\text{V}^*$ $I_C=5\text{A}$, $V_{CE}=1\text{V}^*$ $I_C=10\text{A}$, $V_{CE}=1\text{V}^*$
Transition frequency	f_T		130		MHz	$I_C=100\text{mA}$, $V_{CE}=10\text{V}$ $f=50\text{MHz}$
Output capacitance	C_{OBO}		31		pF	$V_{CB}=10\text{A}$, $f=1\text{MHz}^*$
Switching times	t_{ON} t_{OFF}		42 760		ns	$I_C=1\text{A}$, $V_{CC}=10\text{V}$, $I_{B1}=I_{B2}=100\text{mA}$

NOTES

(1) Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$; duty cycle $\leq 2\%$.

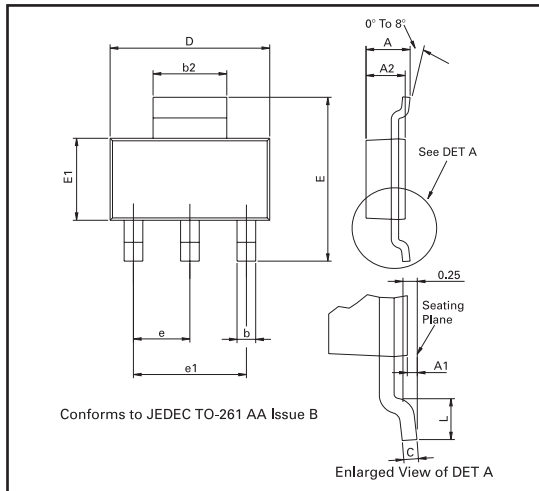
ZX5T851G

TYPICAL CHARACTERISTICS

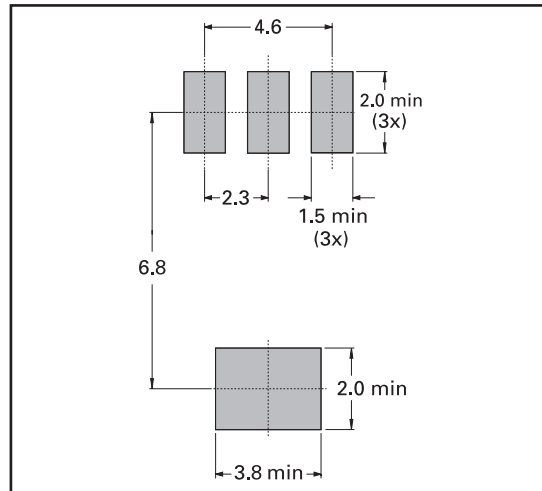


ZX5T851G

PACKAGE OUTLINE



PAD LAYOUT DETAILS



Controlling dimensions are in millimeters. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	-	1.80	-	0.071	e	2.30 BSC		0.0905 BSC	
A1	0.02	0.10	0.0008	0.004	e1	4.60 BSC		0.181 BSC	
b	0.66	0.84	0.026	0.033	E	6.70	7.30	0.264	0.287
b2	2.90	3.10	0.114	0.122	E1	3.30	3.70	0.130	0.146
C	0.23	0.33	0.009	0.013	L	0.90	-	0.355	-
D	6.30	6.70	0.248	0.264	-	-	-	-	-

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